# 2SD2275

### Silicon NPN triple diffusion planar type Darlington

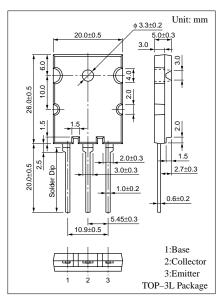
For power amplification Complementary to 2SB1502

#### Features

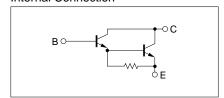
- Optimum for 55W HiFi output
- High foward current transfer ratio h<sub>FE</sub>: 5000 to 30000
- Low collector to emitter saturation voltage V<sub>CE(sat)</sub>: <2.5V</li>

#### Absolute Maximum Ratings (T<sub>C</sub>=25°C)

Parameter	Symbol	Ratings	Unit	
Collector to base voltage	V <sub>CBO</sub>	120	V	
Collector to emitter volta	ge V <sub>CEO</sub>	100	V	
Emitter to base voltage	V <sub>EBO</sub>	5	V	
Peak collector current	$I_{CP}$	8	A	
Collector current	$I_{C}$	5	A	
Collector power T <sub>C</sub> =25		60	***	
dissipation Ta=25	P <sub>C</sub>	3.5	W	
Junction temperature	T <sub>j</sub>	150	°C	
Storage temperature	$T_{stg}$	-55 to +150	°C	



#### Internal Connection



### ■ Electrical Characteristics (T<sub>C</sub>=25°C)

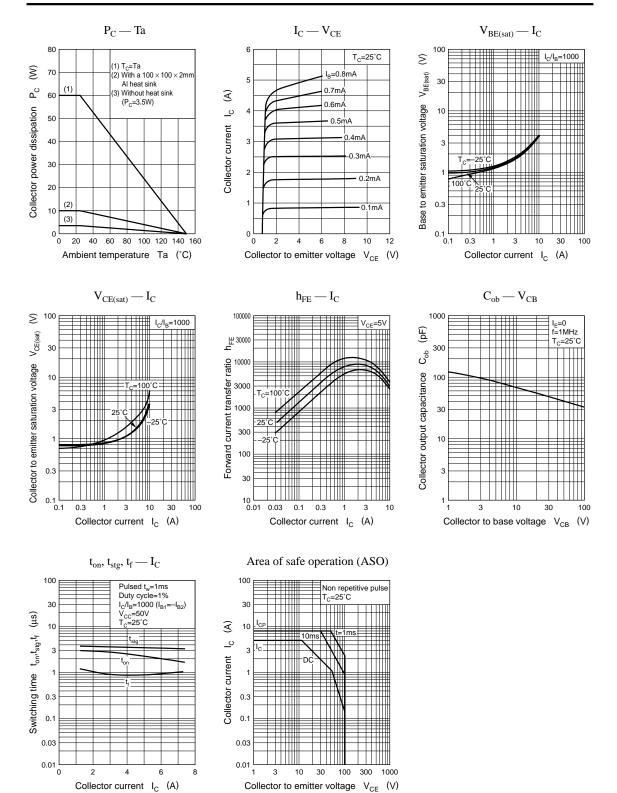
Parameter	Symbol	Conditions	min	typ	max	Unit
Collector cutoff current	$I_{CBO}$	$V_{CB} = 120V, I_E = 0$			100	μΑ
	$I_{CEO}$	$V_{CE} = 100V, I_{B} = 0$			100	μΑ
Emitter cutoff current	$I_{EBO}$	$V_{EB} = 5V, I_{C} = 0$			100	μΑ
Collector to emitter voltage	V <sub>CEO</sub>	$I_C = 30 \text{mA}, I_B = 0$	100			V
Forward current transfer ratio	h <sub>FE1</sub>	$V_{CE} = 5V$ , $I_C = 1A$	2000			
	h <sub>FE2</sub> *	$V_{CE} = 5V$ , $I_C = 4A$	5000		30000	
Collector to emitter saturation voltage	V <sub>CE(sat)</sub>	$I_C = 4A, I_B = 4mA$			2.5	V
Base to emitter saturation voltage	V <sub>BE(sat)</sub>	$I_C = 4A, I_B = 4mA$			3.0	V
Transition frequency	$f_T$	$V_{CE} = 10V, I_{C} = 0.5A, f = 1MHz$		20		MHz
Turn-on time	t <sub>on</sub>	I 4A I 4A I 4A		2.5		μs
Storage time	t <sub>stg</sub>	$I_C = 4A, I_{B1} = 4mA, I_{B2} = -4mA,$		3.5		μs
Fall time	t <sub>f</sub>	$V_{CC} = 50V$		1.0		μs

#### \*h<sub>FE2</sub> Rank classification

Rank	Q	S	P
h <sub>FE2</sub>	5000 to 15000	7000 to 21000	8000 to 30000

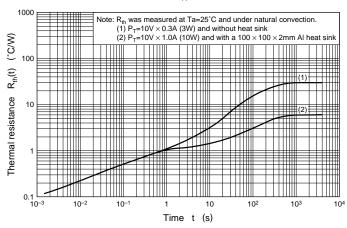
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